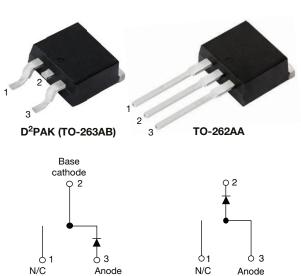
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VS-ETX1506S-M3, VS-ETX1506-1-M3

Vishay Semiconductors

Hyperfast Rectifier, 15 A FRED Pt[®]



VS-ETX1506S-M3 VS-ETX1506-1-M3

PRIMARY CHARACTERISTICS						
I _{F(AV)}	15 A					
V _R	600 V					
V _F at I _F	1.55 V					
t _{rr} (typ.)	18 ns					
T _J max.	175 °C					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Single					

FEATURES

- Hyperfast recovery time, extremely low Qrr
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and qualified according to JEDEC[®]-JESD 47



COMPLIANT

ALOGEN According to

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recover time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	T _C = 127 °C	15	٨			
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	120				
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	600	-	-		
	V _F	I _F = 15 A		2.5	3.4	V	
Forward voltage		I _F = 15 A, T _J = 150 °C	-	1.55	2		
Reverse leakage current	I _R	$V_{R} = V_{R}$ rated	-	0.02	36		
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$		40	250	μA	
Junction capacitance	CT	V _R = 600 V	-	12	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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 1
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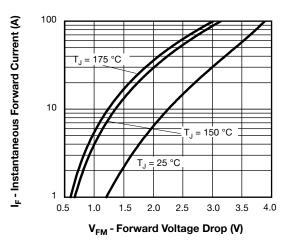


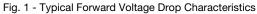
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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 1$	00 A/µs, V _R = 30 V	-	17	23			
Poverse recevent time	t _{rr}	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 1000 $	100 A/µs, V _R = 30 V	-	18	30	ns		
Reverse recovery time	۲r	T _J = 25 °C		-	20	-	115		
		T _J = 125 °C	I _F = 15 A dI _F /dt = 200 A/μs V _B = 390 V	-	45	-			
De als vers aussi aussent	I _{RRM}	T _J = 25 °C		-	2.7	-	А		
Peak recovery current		T _J = 125 °C		-	5.5	-	~		
Reverse recovery charge	0	T _J = 25 °C		-	26	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C -	130	-					
Reverse recovery time	t _{rr}		I _F = 15 A	-	32	-	ns		
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 800 A/µs	-	17	-	А		
Reverse recovery charge	Q _{rr}	V _R = 390 V		-	290	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C		
Thermal resistance, junction to case	R _{thJC}		-	1.3	1.51	°C/W		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70			
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-			
Weight			-	2.0	-	g		
weight			-	0.07	-	oz.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking davias		Case style D ² PAK (TO-263AB) ETX1506		506S				
Marking device		Case style TO-262	ETX1506-1					





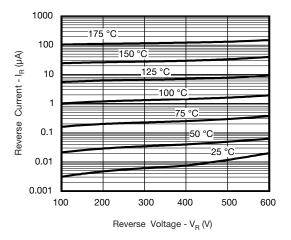


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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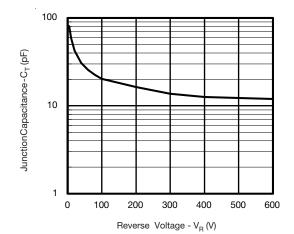


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

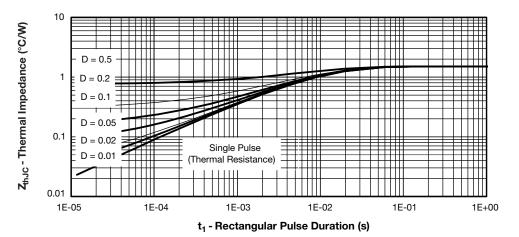
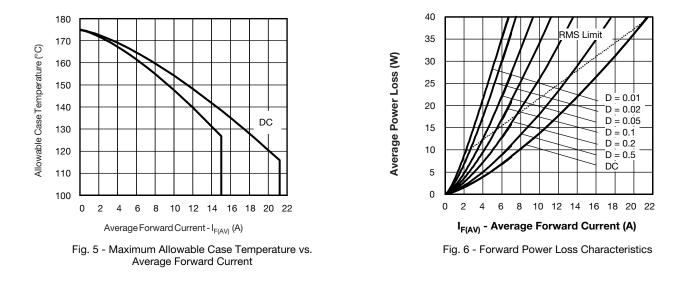


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics



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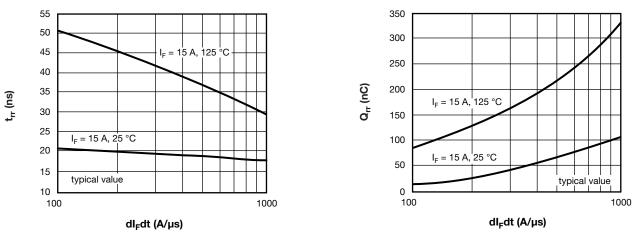


Fig. 7 - Typical Reverse Recovery vs. dl_F/dt

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Fig. 8 - Typical Stored Charge vs. dl_F/dt

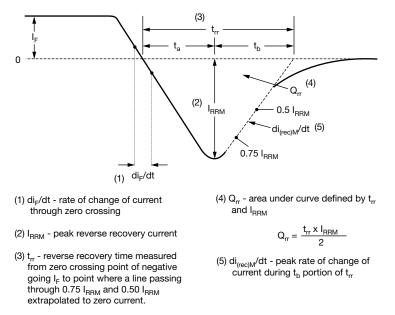


Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code	VS-	E	т	х	15	06	S	TRL	-M3
		2	3	4	5	6	7	8	9
	1 - 2 - 3 - 4 - 5 - 6 - 7 -	 Circ E = T = X = Cur Volt S 	nay Serr suit confi single c TO-220 hyperfa rent coc tage coc = D ² PAI = TO-20	iguration liode st recov le (15 = le (06 = < (TO-2	n rery time 15 A) 600 V)				
	8 -	• No	one = tu	be (50 p					
			RL = tap RR = tap		-				
	9 -	M3	s = halog	gen-free	, RoHS-	complia	ant and	termina	ations le

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-ETX1506S-M3	50	1000	Antistatic plastic tube					
VS-ETX1506-1-M3	50	1000	Antistatic plastic tube					
VS-ETX1506STRR-M3	800	800	13" diameter reel					
VS-ETX1506STRL-M3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164			
	TO-262AA	www.vishay.com/doc?96165			
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444			
	TO-262AA	www.vishay.com/doc?95443			
Packaging information	D ² PAK (TO-263AB)	www.vishay.com/doc?96424			

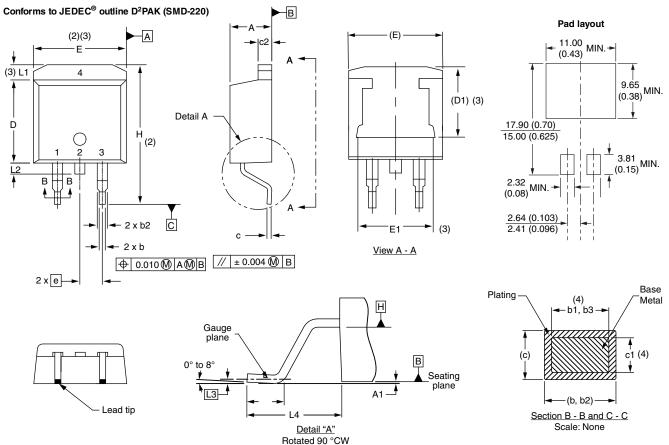
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D²PAK

DIMENSIONS in millimeters and inches

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<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	NOTES	
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	NOTES		
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.100	BSC		
Н	14.61	15.88	0.575	0.625		
L	1.78	2.79	0.070	0.110		
L1	-	1.65	-	0.066	3	
L2	1.27	1.78	0.050	0.070		
L3	0.25 BSC		L3 0.25 BSC 0.010 BSC			
L4	4.78	5.28	0.188	0.208		

.....

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

Controlling dimension: inches (6)

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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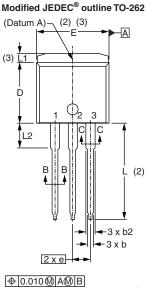
Outline Dimensions

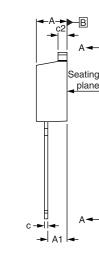


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TO-262AA

DIMENSIONS in millimeters and inches





D1 (3) (3) F1 Section A - A (4) Base Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None

F

0.010 🕅	AM B	



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

SYMBOL	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
 ⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the state back. the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

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